SLOS219F - JUNE 1999 - REVISED DECEMBER 2011

- Wide Bandwidth . . . 10 MHz
- **High Output Drive**
 - I_{OH} . . . 57 mA at V_{DD} 1.5 V - I_{OL} . . . 55 mA at 0.5 V
- **High Slew Rate**
 - SR+...16 V/μs
 - SR-...19 V/μs
- Wide Supply Range . . . 4.5 V to 16 V
- Supply Current . . . 1.9 mA/Channel
- **Ultralow Power Shutdown Mode I**_{DD} . . . 125 μ**A**/Channel
- Low Input Noise Voltage . . . 7 nV \sqrt{Hz} .
- Input Offset Voltage ... 60 µV
- **Ultra-Small Packages**
 - 8 or 10 Pin MSOP (TLC070/1/2/3)

description

The first members of TI's new BiMOS general-purpose operational amplifier family are the TLC07x. The BiMOS family concept is simple: provide an upgrade path for BiFET users who are moving away from dual-supply to single-supply systems and demand higher AC and dc performance. With performance rated from 4.5 V to 16 V across commercial (0°C to 70°C) and an extended industrial temperature range (-40°C to 125°C), BiMOS suits a wide range of audio, automotive, industrial and instrumentation applications. Familiar features like offset nulling pins, and new features like MSOP PowerPAD[™] packages and shutdown modes, enable higher levels of performance in a variety of applications.

Developed in TI's patented LBC3 BiCMOS process, the new BiMOS amplifiers combine a very high input impedance low-noise CMOS front end with a high-drive bipolar output stage, thus providing the optimum performance features of both. AC performance improvements over the TL07x BiFET predecessors include a bandwidth of 10 MHz (an increase of 300%) and voltage noise of 7 nV/\sqrt{Hz} (an improvement of 60%). DC improvements include a factor of 4 reduction in input offset voltage down to 1.5 mV (maximum) in the standard grade, and a power supply rejection improvement of greater than 40 dB to 130 dB. Added to this list of impressive features is the ability to drive ±50-mA loads comfortably from an ultrasmall-footprint MSOP PowerPAD package, which positions the TLC07x as the ideal high-performance general-purpose operational amplifier family.

| FAMILY PACKAGE TABLE | | | | | | | | |
|----------------------|----------|------------|------|---------|-------|----------|-----------------------------------|--|
| DEVICE | NO. OF | D. OF PACK | | E TYPES | | | UNIVERSAL | |
| | CHANNELS | MSOP | PDIP | SOIC | TSSOP | SHUTDOWN | EVM BOARD | |
| TLC070 | 1 | 8 | 8 | 8 | — | Yes | | |
| TLC071 | 1 | 8 | 8 | 8 | — | | | |
| TLC072 | 2 | 8 | 8 | 8 | — | _ | Refer to the EVM | |
| TLC073 | 2 | 10 | 14 | 14 | — | Yes | Selection Guide (Lit# SLOU060) | |
| TLC074 | 4 | _ | 14 | 14 | 20 | _ | , , | |
| TLC075 | 4 | _ | 16 | 16 | 20 | Yes | | |





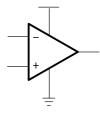
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PowerPAD is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



Operational Amplifier



Copyright © 2000-2011, Texas Instruments Incorporated

SLOS219F - JUNE 1999 - REVISED DECEMBER 2011

TLC070 and TLC071 AVAILABLE OPTIONS

| | PACKAGED DEVICES | | | | | | |
|----------------|-----------------------------------|-------------------------------------|--------------------|------------------------|--|--|--|
| Τ _Α | SMALL OUTLINE (D) [†] | SMALL OUTLINE (DGN) [†] | SYMBOL | PLASTIC DIP (P) | | | |
| 0°C to 70°C | TLC070CD TLC071CD | TLC070CDGN TLC071CDGN | xxTIACS xxTIACU | TLC070CP TLC071CP | | | |
| 4000 1. 40500 | TLC070ID TLC071ID | TLC070IDGN TLC071IDGN | xxTIACT xxTIACV | TLC070IP TLC071IP | | | |
| −40°C to 125°C | TLC070AID TLC071AID | — | — | TLC070AIP TLC071AIP | | | |

[†] This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLC070CDR).

TLC072 and TLC073 AVAILABLE OPTIONS

| | PACKAGED DEVICES | | | | | | | | |
|----------------|-----------------------------|-----------------|---------------------|------------|---------------------|------------|------------|--|--|
| T _A | SMALL MSOP | | | | | PLASTIC | PLASTIC | | |
| | OUTLINE (D) [†] | (DGN)† | SYMBOL [‡] | (DGQ)† | SYMBOL [‡] | DIP (N) | DIP (P) | | |
| 0°C to 70°C | TLC072CD TLC073CD | TLC072CDGN | xxTIADV | | xxTIADX | TLC073CN | TLC072CP | | |
| -40°C to 125°C | TLC072ID TLC073ID | TLC072IDGN — | xxTIADW | TLC073IDGQ | xxTIADY | TLC073IN | TLC072IP | | |
| -40 0 10 125 0 | TLC072AID TLC073AID | | | | | TLC073AIN | TLC072AIP | | |

[†] This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLC072CDR). [‡] xx represents the device date code.

TLC074 and TLC075 AVAILABLE OPTIONS

| | PACKAGED DEVICES | | | | | |
|----------------|------------------|-------------|--------------------|--|--|--|
| Τ _Α | SMALL OUTLINE | PLASTIC DIP | TSSOP | | | |
| | (D) [†] | (N) | (PWP) [†] | | | |
| 0°C to 70°C | TLC074CD | TLC074CN | TLC074CPWP | | | |
| | TLC075CD | TLC075CN | TLC075CPWP | | | |
| -40°C to 125°C | TLC074ID | TLC074IN | TLC074IPWP | | | |
| | TLC075ID | TLC075IN | TLC075IPWP | | | |
| -40 0 10 125 0 | TLC074AID | TLC074AIN | TLC074AIPWP | | | |
| | TLC075AID | TLC075AIN | TLC075AIPWP | | | |

[†] This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLC074CDR).



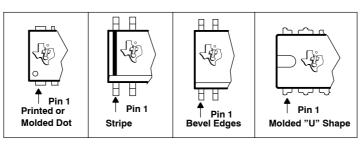
SLOS219F – JUNE 1999 – REVISED DECEMBER 2011

TLC070 TLC071 TI C072 D, DGN OR P PACKAGE D, DGN OR P PACKAGE D, DGN, OR P PACKAGE (TOP VIEW) (TOP VIEW) (TOP VIEW) 10 10 **1**⁰ 8 🖽 NC 10UT 8 🗖 V_{DD} 8 2**4** IN – 🗖 2 7 IN – 🗖 2 7 1IN-- 7 🔲 20UT 🗛 6 🖿 21N -IN + 🗖 IN + 🗖 ι συτ 3-1IN+□ 3-3-GND 🗖 5 GND 🗖 4 5 D NULL GND □ 5 🔲 2IN+ 4 4 **TLC074 TLC073 TLC073 D OR N PACKAGE** DGQ PACKAGE **D OR N PACKAGE** (TOP VIEW) (TOP VIEW) (TOP VIEW) 10UT 🗖 $10 \square V_{DD}$ 14 VDD 10UT 🗖 10UT -14 🔲 40UT 1 - 9 🖽 20UT 1IN – 🗖 2_**4** 13 🗖 20UT 1IN-III 2 1IN- 🗖 8 🗖 2IN-1IN+ □□ з 1IN+ □□ 12 🗖 2IN – 1IN+ 🗖 3 12 🗖 4IN+ 3-GND I 4 7 🖽 2IN+ V_{DD} GND 🔲 2IN+ 4 11 🗖 GND 4 11 ISHDN 6 2SHDN 2IN+ NC I 10 III NC 5 -10 🔲 3IN+ 5 5 9 🖽 3IN – 1SHDN 6 9 2SHDN 2IN-6 NC I 8 II NC 20UT 7 8 🖽 30UT 7 **TLC074 TLC075 TLC075 PWP PACKAGE D OR N PACKAGE PWP PACKAGE** (TOP VIEW) (TOP VIEW) (TOP VIEW) 10UT 🎞 10UT 🗖 -20 🖽 40UT 10 40UT 10UT 🗖 -20 🖽 40UT 16 1 1IN – 🎞 1IN- 🗖 2-19 1 4IN-🔲 41N-1IN- 🗖 19 🗖 4IN-2-15 2 1IN+ 🗖 1IN+ 🗆 3 18 🗖 4IN+ 1IN+ 🗖 3-18 🗖 4IN+ 14 🔲 4IN+ 3 17 🗖 GND 17 🗖 GND 4 GND 4 13 4 16 🗖 3IN+ 2IN+ 🗖 2IN+ 🗖 2IN+ 🗖 16 🗖 3IN+ 5 12 🔲 31N+ 5 5 6₹ **∀**15 2IN-67 15 🗖 3IN-2IN-🔲 3IN-2IN – 🗖 🗖 3IN-6 11 20UT 🗖 7 14 🔲 30UT 20UT 🗖 10 🗂 зоит 20UT 🗖 7 14 🖽 30UT 7 13 🗖 NC 8 1/2SHDN 3/4SHDN 1/2SHDN 8 13 3/4SHDN 8 9 12 D NC 9 9 12 D NC NC 🗖 10 11 🗖 NC 10 11 🗖 NC

TLC07x PACKAGE PIN OUTS

NC - No internal connection

TYPICAL PIN 1 INDICATORS





SLOS219F - JUNE 1999 - REVISED DECEMBER 2011

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

| Supply voltage, V _{DD} (see Note 1) Differential input voltage range, V _{ID} | |
|---|----------------|
| Continuous total power dissipation | |
| Operating free-air temperature range, T _A : C suffix | 0°C to 70°C |
| I suffix | –40°C to 125°C |
| Maximum junction temperature, T _J | 150°C |
| Storage temperature range, T _{stg} | |
| Lead temperature 1,6 mm (1/16 inch) from case for 10 se | |

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values, except differential voltages, are with respect to GND.

| PACKAGE | ^θ јс (°С/W) | θ _{JA} (°C/W) | T _A ≤ 25°C POWER BATING |
|------------|---------------------------|---------------------------|---------------------------------------|
| D (9) | 38.3 | 176 | 710 mW |
| D (8) | | | |
| D (14) | 26.9 | 122.3 | 1022 mW |
| D (16) | 25.7 | 114.7 | 1090 mW |
| DGN (8) | 4.7 | 52.7 | 2.37 W |
| DGQ (10) | 4.7 | 52.3 | 2.39 W |
| N (14, 16) | 32 | 78 | 1600 mW |
| P (8) | 41 | 104 | 1200 mW |
| PWP (20) | 1.40 | 26.1 | 4.79 W |

recommended operating conditions

| | | MIN | MAX | UNIT | |
|--|-----------------|-------|--|------|--|
| | Single supply | 4.5 | 16 | | |
| Supply voltage, V _{DD} | Split supply | ±2.25 | 4.5 16 ±2.25 ±8 +0.5 V _{DD} -0.8 2 0.8 0 70 | V | |
| Common-mode input voltage, VICR | | +0.5 | V _{DD} -0.8 | .8 V | |
| Shutdown on/off voltage level [‡] | V _{IH} | 2 | | v | |
| Shudown on/on volage level* | V _{OL} | | 4.5 16 ±2.25 ±8 +0.5 V _{DD} −0.8 2 0.8 | v | |
| Operating free-air temperature, T _A C-suffix I-suffix | C-suffix | 0 | 70 | °C | |
| | -40 | 125 | C | | |

[‡] Relative to the voltage on the GND terminal of the device.



SLOS219F – JUNE 1999 – REVISED DECEMBER 2011

| | PARAMETER | TEST CON | TEST CONDITIONS | | MIN | ТҮР | MAX | UNIT |
|------------------|---|--|---------------------------|------------------|------------------|------|------|----------|
| | | | TLC070/1/2/3, | | | 390 | 1900 | |
| | | V _{DD} = 5 V, | TLC074/5 | Full range | | | 3000 | |
| V _{IO} | Input offset voltage | $V_{\rm IC} = 2.5 \text{ V},$ | TLC070/1/2/3A, | 25°C | | 390 | 1400 | μV |
| | | V _O = 2.5 V, | TLC074/5A | Full range | | | 2000 | |
| αNO | Temperature coefficient of input offset voltage | R _S = 50 Ω | | | | 1.2 | | μV/°C |
| | | | | 25°C | | 0.7 | 50 | |
| l _{iO} | Input offset current | V _{DD} = 5 V, | TLC07XC | | | | 100 | pА |
| | | $V_{DD} = 3 V,$ $V_{IC} = 2.5 V,$ | TLC07XI | Full range | | | 700 | |
| | | V _O = 2.5 V, | | 25°C | | 1.5 | 50 | |
| I _{IB} | Input bias current | R _S = 50 Ω | TLC07XC | | | | 100 | pА |
| | | | TLC07XI | Full range | | | 700 | |
| V _{ICR} | Common-mode input voltage | R _S = 50 Ω | | 25°C | 0.5 to 4.2 | | | v |
| | | | | Full range | 0.5 to 4.2 | | | • |
| | High-level output voltage | V _{IC} = 2.5 V | | 25°C | 4.1 | 4.3 | | v |
| | | | I _{OH} = – 1 mA | Full range | 3.9 | | | |
| | | | L 20 mA | 25°C | 3.7 | 4 | | |
| | | | I _{OH} = -20 mA | Full range | 3.5 | | | |
| V _{OH} | | | I _{OH} = -35 mA | 25°C | 3.4 | 3.8 | | |
| | | | | Full range | 3.2 | | | |
| | | | I _{OH} = – 50 mA | 25°C | 3.2 | 3.6 | | |
| | | | | -40°C to 85°C | 3 | | | |
| | | | I _{OL} = 1 mA | 25°C | | 0.18 | 0.25 | |
| | | | | Full range | | | 0.35 | - |
| | | | I _{OL} = 20 mA | 25°C | | 0.35 | 0.39 | |
| | | | IOT = 50 IIIX | Full range | | | 0.45 | |
| V _{OL} | Low-level output voltage | V _{IC} = 2.5 V | I _{OL} = 35 mA | 25°C | | 0.43 | 0.55 | V |
| | | | 10L = 33 IIIX | Full range | | | 0.7 | |
| | | | | 25°C | | 0.48 | 0.63 | |
| | | I _{OL} = 50 mA | | -40°C to 85°C | | | 0.7 | |
| | | Sourcing | Sourcing | | | 100 | | mA |
| os | Short-circuit output current | Sinking | | 25°C | | 100 | | |
| | | V _{OH} = 1.5 V from positive rail | | 25°C | | 57 | | <u> </u> |
| lo | Output current | V _{OL} = 0.5 V from nega | 25°C | | 55 | | mA | |

[†] Full range is 0°C to 70°C for C suffix and -40°C to 125°C for I suffix. If not specified, full range is -40°C to 125°C.



SLOS219F - JUNE 1999 - REVISED DECEMBER 2011

electrical characteristics at specified free-air temperature, V_{DD} = 5 V (unless otherwise noted) (continued)

| PARAMETER | | TEST CON | DITIONS | T _A † | MIN | TYP | MAX | UNIT |
|-------------------|--|----------------------------------|-----------------------|------------------|-----|------|-----|------|
| | Large-signal differential voltage | N 0.V | D 4010 | 25°C | 100 | 120 | | |
| A _{VD} | amplification | V _{O(PP)} = 3 V, | $R_L = 10 \ k\Omega$ | Full range | 100 | | | dB |
| r _{i(d)} | Differential input resistance | | | 25°C | | 1000 | | GΩ |
| C _{IC} | Common-mode input capacitance | f = 10 kHz | | 25°C | | 22.9 | | pF |
| z _o | Closed-loop output impedance | f = 10 kHz, | A _V = 10 | 25°C | | 0.25 | | Ω |
| | | | R _S = 50 Ω | 25°C | 80 | 95 | | -10 |
| CMRR | Common-mode rejection ratio | V _{IC} = 1 to 3 V, | | Full range | 80 | | | dB |
| 1. | Supply voltage rejection ratio | V _{DD} = 4.5 V to 16 V, | $V_{IC} = V_{DD}/2,$ | 25°C | 80 | 100 | | ٩Ŀ |
| k _{SVR} | $(\Delta V_{DD} / \Delta V_{IO})$ | No load | | Full range | 80 | | | dB |
| I | Supply surrent (per channel) | | No load | 25°C | | 1.9 | 2.5 | mA |
| IDD | Supply current (per channel) | V _O = 2.5 V, | no loau | Full range | | | 3.5 | ША |
| | Supply current in shutdown | | | 25°C | | 125 | 200 | |
| IDD(SHDN) | mode (per channel) (TLC070, TLC073, TLC075) | <u>SHDN</u> ≤ 0.8 V | | Full range | | | 250 | μA |

⁺ Full range is 0°C to 70°C for C suffix and -40°C to 125°C for I suffix. If not specified, full range is -40°C to 125°C.



SLOS219F – JUNE 1999 – REVISED DECEMBER 2011

| operating characteristics at specified free-air temp | perature, V _{DD} = 5 V (unless otherwise noted) |
|--|--|
|--|--|

| • | • | - | | | | | | - | |
|--------------------|--------------------------------------|--|-------------------------|------------------|------|--------|-----|--------------|--|
| | PARAMETER | TEST CONDI | TIONS | Τ _Α † | MIN | ТҮР | MAX | UNIT | |
| SR+ | Positive slew rate at unity gain | V _{O(PP)} = 0.8 V, | C _L = 50 pF, | 25°C | 10 | 16 | | V/µs | |
| Sn+ | Fositive siew rate at unity gain | $R_L = 10 k\Omega$ | | Full range | 9.5 | | | v/µs | |
| SR- | R- Negative slew rate at unity gain | V _{O(PP)} = 0.8 V, | C _L = 50 pF, | 25°C | 12.5 | 19 | | V/µs | |
| | Negative siew rate at unity gain | $R_L = 10 k\Omega$ | | Full range | 10 | | | ν /μ3 | |
| Vn | Equivalent input noise voltage | f = 100 Hz | | 25°C | | 12 | | nV/√Hz | |
| ۷n | Equivalent input hoise voltage | f = 1 kHz | | 25°C | | 7 | | 110/112 | |
| In | Equivalent input noise current | f = 1 kHz | | 25°C | | 0.6 | | fA/√Hz | |
| | | V _{O(PP)} = 3 V, | $A_V = 1$ | | | 0.002% | | | |
| THD + N | Total harmonic distortion plus noise | $R_L = 10 \text{ k}\Omega$ and 250 Ω , | A _V = 10 | 25°C | | 0.012% | | | |
| | | f = 1 kHz | A _V = 100 | | | 0.085% | | | |
| t _(on) | Amplifier turn-on time [‡] | | | 25°C | | 0.15 | | μs | |
| t _(off) | Amplifier turn-off time [‡] | $R_L = 10 k\Omega$ | | 25°C | | 1.3 | | μs | |
| | Gain-bandwidth product | f = 10 kHz, | $R_L = 10 \ k\Omega$ | 25°C | | 10 | | MHz | |
| | | $V_{(STEP)PP} = 1 V,$ $A_V = -1,$ | 0.1% | | | 0.18 | | μs | |
| t _s | Settling time | C _L = 10 pF, R _L = 10 kΩ | 0.01% | 25°C | | 0.39 | | | |
| ۲S | | $V_{(STEP)PP} = 1 V,$ $A_V = -1,$ | 0.1% | 23 0 | | 0.18 | | | |
| | | $C_L = 47 \text{ pF},$ $R_L = 10 \text{ k}\Omega$ | 0.01% | | | 0.39 | | | |
| | | $R_L = 10 \text{ k}\Omega$, | $C_L = 50 \text{ pF}$ | 05%0 | | 32° | | | |
| φm | Phase margin | $R_L = 10 \text{ k}\Omega$, | C _L = 0 pF | 25°C | | 40° | | | |
| | Osia mania | $R_L = 10 \text{ k}\Omega$, | C _L = 50 pF | 0500 | | 2.2 | | 40 | |
| | Gain margin | R _L = 10 kΩ, | C _L = 0 pF | 25°C | | 3.3 | | dB | |

[†] Full range is 0°C to 70°C for C suffix and -40°C to 125°C for I suffix. If not specified, full range is -40°C to 125°C.

[‡] Disable time and enable time are defined as the interval between application of the logic signal to SHDN and the point at which the supply current has reached half its final value.



TLC070, TLC071, TLC072, TLC073, TLC074, TLC075, TLC07xA FAMILY OF WIDE-BANDWIDTH HIGH-OUTPUT-DRIVE SINGLE SUPPLY **OPERATIONAL AMPLIFIERS** SLOS219F – JUNE 1999 – REVISED DECEMBER 2011

electrical characteristics at specified free-air temperature, V_{DD} = 12 V (unless otherwise noted)

| | PARAMETER | TEST CONI | DITIONS | T _A † | MIN | ТҮР | MAX | UNIT |
|------------------|---|-------------------------------------|---------------------------|------------------|-------------------|------|------|-------|
| | | | TLC070/1/2/3, | 25°C | | 390 | 1900 | |
| | | V _{DD} = 12 V | TLC074/5 | Full range | | | 3000 | ., |
| V _{IO} | Input offset voltage | $V_{\text{IC}} = 6 \text{ V},$ | TLC070/1/2/3A, | 25°C | | 390 | 1400 | μV |
| | | V _O = 6 V, | TLC074/5A | Full range | | | 2000 | |
| αVIO | Temperature coefficient of input offset voltage | R _S = 50 Ω | | | | 1.2 | | μV/°C |
| | | | | 25°C | | 0.7 | 50 | |
| l _{io} | Input offset current | V 10.V | TLC07xC | | | | 100 | pА |
| | | $V_{DD} = 12 V$ $V_{IC} = 6 V$, | TLC07xl | Full range | | | 700 | - |
| | | V _O = 6 V, | | 25°C | | 1.5 | 50 | |
| I _{IB} | Input bias current | R _S = 50 Ω | TLC07xC | | | | 100 | pА |
| | | | TLC07xl | Full range | | | 700 | |
| v | Common mode input veltage | D 50.0 | | 25°C | 0.5 to 11.2 | | | V |
| V _{ICR} | Common-mode input voltage | R _S = 50 Ω | | Full range | 0.5 to 11.2 | | | V |
| | | | 1 1 - 1 | 25°C | 11.1 | 11.2 | | |
| | | | I _{OH} = – 1 mA | Full range | 11 | | | |
| | | | L 00 mA | 25°C | 10.8 | 10.9 | | |
| | | | I _{OH} = – 20 mA | Full range | 10.7 | | | |
| V _{OH} | High-level output voltage | $V_{IC} = 6 V$ | 1 05 mA | 25°C | 10.6 | 10.7 | | V |
| | | | I _{OH} = -35 mA | Full range | 10.3 | | | |
| | | | | 25°C 10.4 | | 10.5 | | |
| | | | I _{OH} = – 50 mA | -40°C to 85°C | 10.3 | | | |
| | | | I _{OL} = 1 mA | 25°C | | 0.17 | 0.25 | |
| | | | | Full range | | | 0.35 | |
| | | | I _{OL} = 20 mA | 25°C | | 0.35 | 0.45 | |
| | | | 10L - 20 MA | Full range | | | 0.5 | |
| V _{OL} | Low-level output voltage | V _{IC} = 6 V | I _{OL} = 35 mA | 25°C | | 0.4 | 0.52 | V |
| | | | 10L - 03 IIIA | Full range | | | 0.6 | |
| | | | | 25°C | | 0.45 | 0.6 | |
| | | | I _{OL} = 50 mA | -40°C to 85°C | | | 0.65 | |
| | | Sourcing | | 25°C | | 150 | | |
| os | Short-circuit output current | Sinking | | 25°C | | 150 | | mA |
| | | V _{OH} = 1.5 V from posit | ive rail | 25°C | | 57 | | |
| lo | Output current | V _{OL} = 0.5 V from nega | tive rail | 25°C | | 55 | | mA |

⁺ Full range is 0°C to 70°C for C suffix and -40°C to 125°C for I suffix. If not specified, full range is -40°C to 125°C.



SLOS219F - JUNE 1999 - REVISED DECEMBER 2011

electrical characteristics at specified free-air temperature, V_{DD} = 12 V (unless otherwise noted) (continued)

| | PARAMETER | TEST CON | DITIONS | T _A † | MIN | TYP | MAX | UNIT |
|-------------------|--|----------------------------------|-----------------------|------------------|-----|------|-----|------|
| • | Large-signal differential voltage | N 0.V | D 1010 | 25°C | 120 | 140 | | - UL |
| A _{VD} | amplification | V _{O(PP)} = 8 V, | $R_L = 10 k\Omega$ | Full range | 120 | | | dB |
| r _{i(d)} | Differential input resistance | | | 25°C | | 1000 | | GΩ |
| C _{IC} | Common-mode input capacitance | f = 10 kHz | | 25°C | | 21.6 | | pF |
| z _o | Closed-loop output impedance | f = 10 kHz, | A _V = 10 | 25°C | | 0.25 | | Ω |
| OMDD | | | D 50 0 | 25°C | 80 | 100 | | -10 |
| CMRR | Common-mode rejection ratio | V _{IC} = 1 to 10 V, | R _S = 50 Ω | Full range | 80 | | | dB |
| 1. | Supply voltage rejection ratio | V _{DD} = 4.5 V to 16 V, | $V_{IC} = V_{DD}/2,$ | 25°C | 80 | 100 | | ЧР |
| k _{SVR} | $(\Delta V_{DD} / \Delta V_{IO})$ | No load | | Full range | 80 | | | dB |
| | Supply surrent (nor shannel) | | No load | 25°C | | 2.1 | 2.9 | mA |
| DD | Supply current (per channel) | V _O = 7.5 V, | NO IOAU | Full range | | | 3.5 | ША |
| | Supply current in shutdown mode (TLC070, TLC073, | <u>SHDN</u> < 0.8 V | | 25°C | | 125 | 200 | A |
| IDD(SHDN) | TLC075) (per channel) | אוטח∂ ⊻ 0.8 V | | Full range | | | 250 | μA |

[†] Full range is 0°C to 70°C for C suffix and -40°C to 125°C for I suffix. If not specified, full range is -40°C to 125°C.



SLOS219F - JUNE 1999 - REVISED DECEMBER 2011

operating characteristics at specified free-air temperature, V_{DD} = 12 V (unless otherwise noted)

| | PARAMETER | TEST CONDI | TIONS | T _A † | MIN | ТҮР | MAX | UNIT |
|--------------------|--------------------------------------|--|-------------------------|------------------|------|-------------|-----|---------|
| SR+ | Desitive eleverate et unity asia | V _{O(PP)} = 2 V, | C _L = 50 pF, | 25°C | 10 | 16 | | |
| 5K+ | Positive slew rate at unity gain | $R_L = 10 k\Omega$ | | Full range | 9.5 | | | V/µs |
| SR- | Negative slew rate at unity gain | V _{O(PP)} = 2 V, | C _L = 50 pF, | 25°C | 12.5 | 19 | | V/μs |
| on- | Negative siew rate at unity gain | $R_L = 10 k\Omega$ | | Full range | 10 | | | v/µs |
| V | Equivalent input noise voltage | f = 100 Hz | | 25°C | | 12 | | nV/√Hz |
| Vn | Equivalent input hoise voltage | f = 1 kHz | | 25°C | | 7 | | 110/112 |
| I _n | Equivalent input noise current | f = 1 kHz | | 25°C | | 0.6 | | fA/√Hz |
| | | V _{O(PP)} = 8 V, | A _V = 1 | | | 0.002% | | |
| THD + N | Total harmonic distortion plus noise | $R_L = 10 \text{ k}\Omega$ and 250 Ω , | A _V = 10 | 25°C | | 0.005% | | |
| | | f = 1 kHz | A _V = 100 | | | 0.022% | | |
| t _(on) | Amplifier turn-on time [‡] | | | 25°C | | 0.47 | | μs |
| t _(off) | Amplifier turn-off time [‡] | R _L = 10 kΩ | | 25°C | | 2.5 | | μs |
| | Gain-bandwidth product | f = 10 kHz, | $R_L = 10 \ k\Omega$ | 25°C | | 10 | | MHz |
| | | $V_{(STEP)PP} = 1 V,$ $A_V = -1,$ | 0.1% | | | 0.17 | | |
| t _s | Settling time | C _L = 10 pF, R _L = 10 kΩ | 0.01% | 25°C | | 0.22 | | μŝ |
| LS | | $V_{(STEP)PP} = 1 V,$ $A_V = -1,$ | 0.1% | 23 0 | | 0.17 | | μσ |
| | | $C_L = 47 \text{ pF},$ $R_L = 10 \text{ k}\Omega$ | 0.01% | | | 0.29 | | |
| * | Dhoop morein | $R_L = 10 \text{ k}\Omega$, | C _L = 50 pF | 05%0 | | 37 ° | | |
| φm | Phase margin | R _L = 10 kΩ, | C _L = 0 pF | 25°C | | 42° | | |
| | 0.1 | R _L = 10 kΩ, | C _L = 50 pF | 0500 | | 3.1 | | JD |
| | Gain margin | R _I = 10 kΩ, | C _L = 0 pF | 25°C | | 4 | | dB |

[†] Full range is 0°C to 70°C for C suffix and -40°C to 125°C for I suffix. If not specified, full range is -40°C to 125°C.

[‡] Disable time and enable time are defined as the interval between application of the logic signal to SHDN and the point at which the supply current has reached half its final value.



SLOS219F - JUNE 1999 - REVISED DECEMBER 2011

TYPICAL CHARACTERISTICS

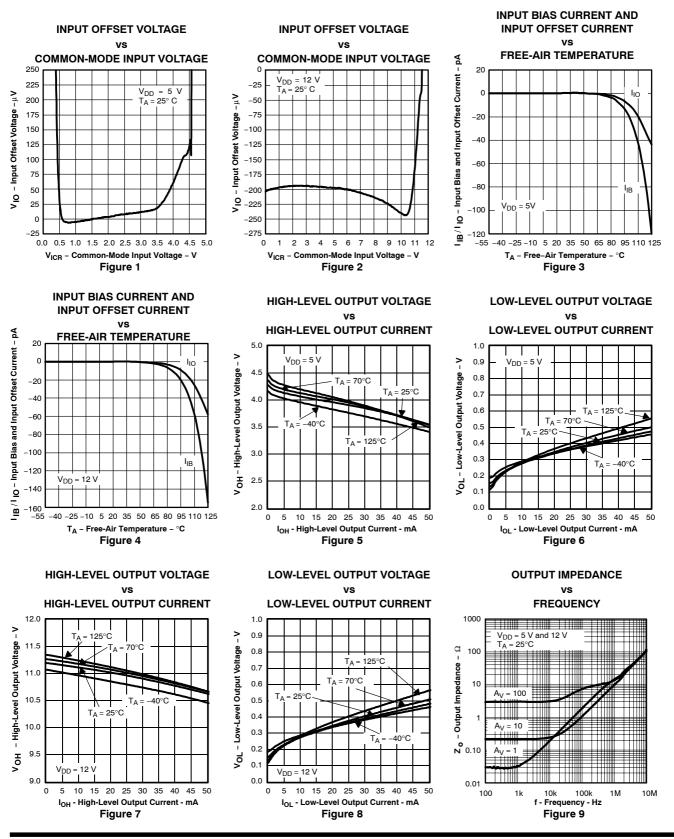
Table of Graphs

| | | | FIGURE |
|--------------------|---------------------------------------|--|--------------|
| V _{IO} | Input offset voltage | vs Common-mode input voltage | 1, 2 |
| I _{IO} | Input offset current | vs Free-air temperature | 3, 4 |
| I _{IB} | Input bias current | vs Free-air temperature | 3, 4 |
| V _{OH} | High-level output voltage | vs High-level output current | 5, 7 |
| V _{OL} | Low-level output voltage | vs Low-level output current | 6, 8 |
| Zo | Output impedance | vs Frequency | 9 |
| I _{DD} | Supply current | vs Supply voltage | 10 |
| PSRR | Power supply rejection ratio | vs Frequency | 11 |
| CMRR | Common-mode rejection ratio | vs Frequency | 12 |
| V _n | Equivalent input noise voltage | vs Frequency | 13 |
| V _{O(PP)} | Peak-to-peak output voltage | vs Frequency | 14, 15 |
| | Crosstalk | vs Frequency | 16 |
| | Differential voltage gain | vs Frequency | 17, 18 |
| | Phase | vs Frequency | 17, 18 |
| φm | Phase margin | vs Load capacitance | 19, 20 |
| | Gain margin | vs Load capacitance | 21, 22 |
| | Gain-bandwidth product | vs Supply voltage | 23 |
| SR | Slew rate | vs Supply voltage vs Free-air temperature | 24 25, 26 |
| | | vs Frequency | 27, 28 |
| THD + N | Total harmonic distortion plus noise | vs Peak-to-peak output voltage | 29, 30 |
| | Large-signal follower pulse response | | 31, 32 |
| | Small-signal follower pulse response | | 33 |
| | Large-signal inverting pulse response | | 34, 35 |
| | Small-signal inverting pulse response | | 36 |
| | Shutdown forward isolation | vs Frequency | 37, 38 |
| | Shutdown reverse isolation | vs Frequency | 39, 40 |
| | | vs Supply voltage | 41 |
| | Shutdown supply current | vs Free-air temperature | 42 |
| | Shutdown pulse | | 43, 44 |

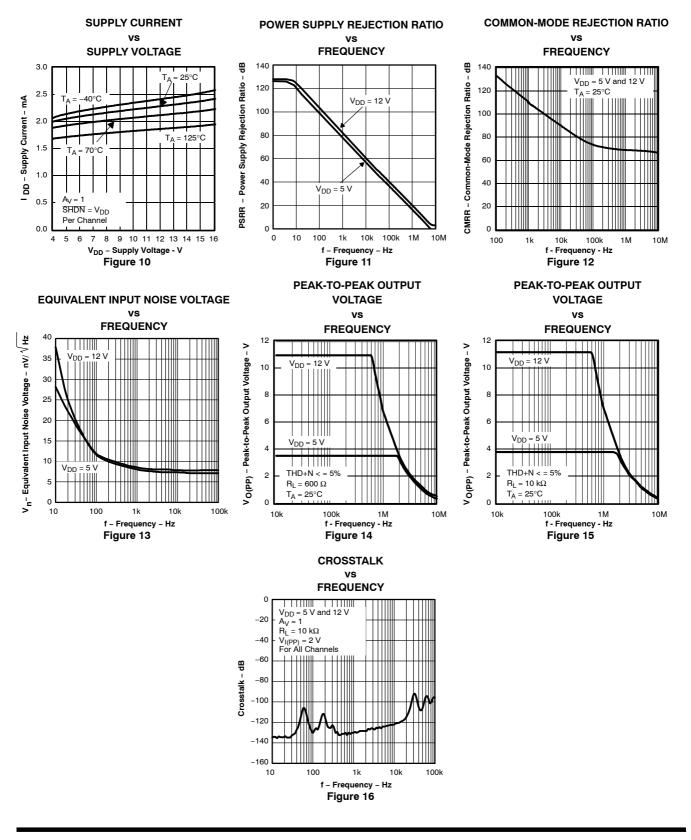


SLOS219F - JUNE 1999 - REVISED DECEMBER 2011

TYPICAL CHARACTERISTICS

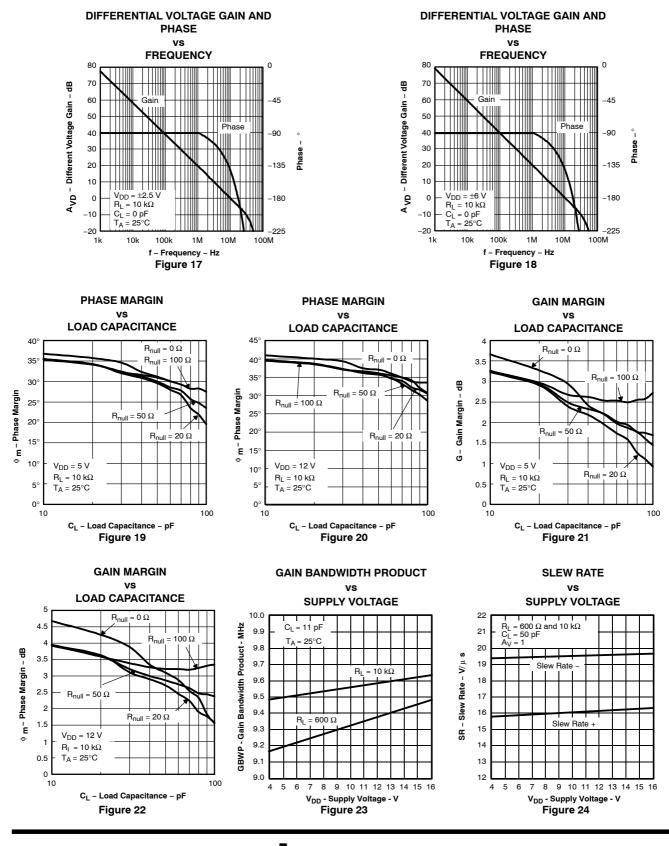


SLOS219F – JUNE 1999 – REVISED DECEMBER 2011

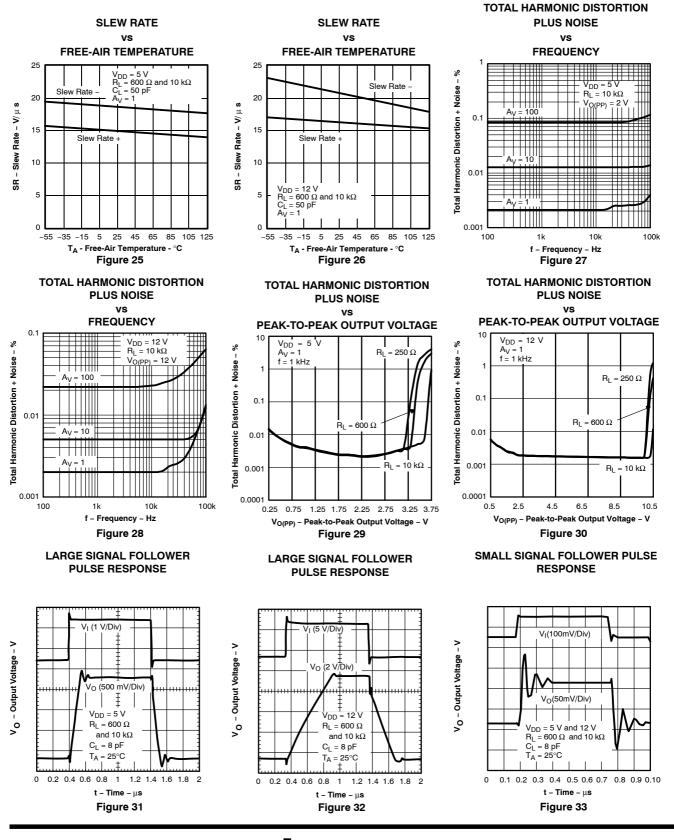




SLOS219F - JUNE 1999 - REVISED DECEMBER 2011



SLOS219F – JUNE 1999 – REVISED DECEMBER 2011



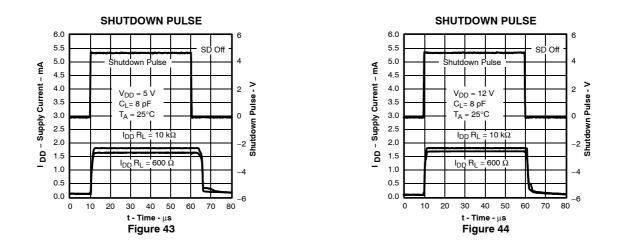


SLOS219F - JUNE 1999 - REVISED DECEMBER 2011

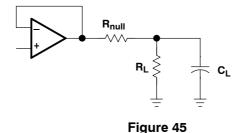
LARGE SIGNAL INVERTING LARGE SIGNAL INVERTING SMALL SIGNAL INVERTING **PULSE RESPONSE PULSE RESPONSE PULSE RESPONSE** V_I (2 V/div) V₁ (5 V/div) V_I (100 mV/div) V_O - Output Voltage - V # V _O - Output Voltage - V V _O - Output Voltage - V 1 V_{DD} = 5 & 12 V R_L = 600 Ω and 10 $k\Omega$ $V_{DD} = 5 V$ V_{DD} = 12 V C_L = 8 pF $R_L = 600 \ \Omega$ $R_L = 600 \Omega$ $T_A = 25^{\circ}C$ and 10 $k\Omega$ and 10 k Ω C_L = 8 pF C_L = 8 pF $T_A = 25^{\circ}C$ T_A = 25°C V_O (50 mV/Div V_O (500 mV/Div) V_O (2 V/Div) 0.2 0.4 0.6 0.8 1.2 1.4 1.6 1.8 2 0 0.2 0.4 0.6 0.8 1 1.2 1.4 1.6 1.8 2 0 0.1 0.2 0.3 0.4 0.5 0.6 0.7 0.8 0.9 1 1 0 t – Time – μs t - Time - µs t – Time – μs Figure 34 Figure 35 Figure 36 SHUTDOWN FORWARD SHUTDOWN FORWARD SHUTDOWN REVERSE ISOLATION ISOLATION ISOLATION vs vs vs FREQUENCY FREQUENCY FREQUENCY 140 140 140 V_{DD} = 5 V V_{DD} = 5 V $V_{DD} = 12 V$ C_L= 0 pF Sutdown Forward Isolation - dB 뜅 C_L= 0 pF -аВ 120 120 CL= 0 pF 120 $T_A = 25^{\circ}C$ $T_A = 25^{\circ}C$ $T_A = 25^{\circ}C$ Sutdown Forward Isolation V_{I(PP)} = 0.1, 2.5, and 5 V V_{I(PP)} = 0.1, 2.5, and 5 V Sutdown Reverse Isolation V_{I(PP)} = 0.1, 8, and 12 V 111100 11111 100 100 100 RL 600 Q 80 80 80 = 600 Ω R R = 600 Ω 60 60 R = 10 kΩ 60 = 10 kΩ $R_L = 10 \ k\Omega$ R_L 40 40 40 20 20 20 100 1k 10k 10k 100k 1M f - Frequency - Hz 10M 100M 100 1k 10k 100k 1M f - Frequency - Hz 10M 100M 100 1k 10k 10k 100k 1M f - Frequency - Hz 10M 100M Figure 37 Figure 38 Figure 39 SHUTDOWN REVERSE SHUTDOWN SUPPLY CURRENT SHUTDOWN SUPPLY CURRENT ISOLATION vs vs vs SUPPLY VOLTAGE **FREE-AIR TEMPERATURE** FREQUENCY 140 DD(SHDN) - Shutdown Supply Current - µ A 136 DD(SHDN) - Shutdown Supply Current - µ A 180 $A_V = 1$ $V_{IN} = V_{DD/2}$ V_{DD} = 12 V Shutdown On 134 R_L = open V_{IN} = V_{DD/2} C_L= 0 pF 뜅 120 160 $T_A = 25^{\circ}C$ 132 Sutdown Reverse Isolation V_{I(PP)} = 0.1, 8, and 12 V 140 100 130 V_{DD} = 12 V 128 80 600 Ω 120 126 V_{DD} = 5 V 60 124 100 R_L = 10 kΩ 122 40 80 120 20 118 60 9 10 11 12 13 14 15 16 -55 10k 100k IV f - Frequency - Hz 4 5 6 7 8 -25 5 35 65 95 125 100 10M 100M 1 k V_{DD} - Supply Voltage - V T_A - Free-Air Temperature - °C Figure 40 Figure 41 Figure 42

SLOS219F - JUNE 1999 - REVISED DECEMBER 2011

TYPICAL CHARACTERISTICS



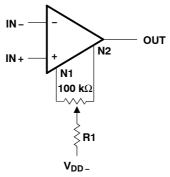
PARAMETER MEASUREMENT INFORMATION





input offset voltage null circuit

The TLC070 and TLC071 has an input offset nulling function. Refer to Figure 46 for the diagram.



NOTE A: R1 = 5.6 k Ω for offset voltage adjustment of ±10 mV. R1 = 20 k Ω for offset voltage adjustment of ±3 mV.

Figure 46. Input Offset Voltage Null Circuit



SLOS219F - JUNE 1999 - REVISED DECEMBER 2011

APPLICATION INFORMATION

driving a capacitive load

When the amplifier is configured in this manner, capacitive loading directly on the output will decrease the device's phase margin leading to high frequency ringing or oscillations. Therefore, for capacitive loads of greater than 10 pF, it is recommended that a resistor be placed in series (R_{NULL}) with the output of the amplifier, as shown in Figure 47. A minimum value of 20 Ω should work well for most applications.

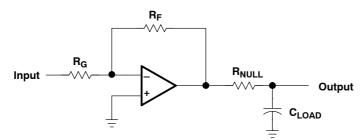


Figure 47. Driving a Capacitive Load

offset voltage

The output offset voltage, (V_{OO}) is the sum of the input offset voltage (V_{IO}) and both input bias currents (I_{IB}) times the corresponding gains. The following schematic and formula can be used to calculate the output offset voltage:

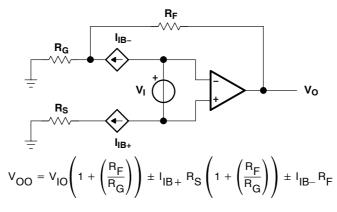


Figure 48. Output Offset Voltage Model



SLOS219F - JUNE 1999 - REVISED DECEMBER 2011

APPLICATION INFORMATION

high speed CMOS input amplifiers

The TLC07x is a family of high-speed low-noise CMOS input operational amplifiers that has an input capacitance of the order of 20 pF. Any resistor used in the feedback path adds a pole in the transfer function equivalent to the input capacitance multiplied by the combination of source resistance and feedback resistance. For example, a gain of –10, a source resistance of 1 k Ω , and a feedback resistance of 10 k Ω add an additional pole at approximately 8 MHz. This is more apparent with CMOS amplifiers than bipolar amplifiers due to their greater input capacitance.

This is of little consequence on slower CMOS amplifiers, as this pole normally occurs at frequencies above their unity-gain bandwidth. However, the TLC07x with its 10-MHz bandwidth means that this pole normally occurs at frequencies where there is on the order of 5 dB gain left and the phase shift adds considerably.

The effect of this pole is the strongest with large feedback resistances at small closed loop gains. As the feedback resistance is increased, the gain peaking increases at a lower frequency and the 180° phase shift crossover point also moves down in frequency, decreasing the phase margin.

For the TLC07x, the maximum feedback resistor recommended is 5 k Ω ; larger resistances can be used but a capacitor in parallel with the feedback resistor is recommended to counter the effects of the input capacitance pole.

The TLC073 with a 1-V step response has an 80% overshoot with a natural frequency of 3.5 MHz when configured as a unity gain buffer and with a $10-k\Omega$ feedback resistor. By adding a 10-pF capacitor in parallel with the feedback resistor, the overshoot is reduced to 40% and eliminates the natural frequency, resulting in a much faster settling time (see Figure 49). The 10-pF capacitor was chosen for convenience only.

Load capacitance had little effect on these measurements due to the excellent output drive capability of the TLC07x.

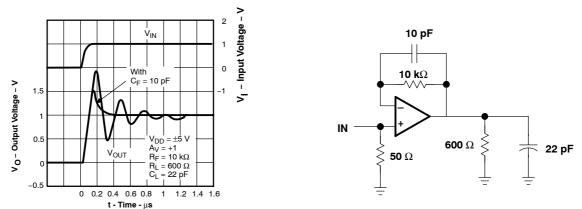


Figure 49. 1-V Step Response



SLOS219F - JUNE 1999 - REVISED DECEMBER 2011

APPLICATION INFORMATION

general configurations

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to accomplish this is to place an RC filter at the noninverting terminal of the amplifier (see Figure 50).

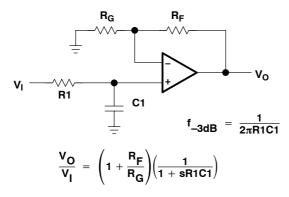


Figure 50. Single-Pole Low-Pass Filter

If even more attenuation is needed, a multiple pole filter is required. The Sallen-Key filter can be used for this task. For best results, the amplifier should have a bandwidth that is 8 to 10 times the filter frequency bandwidth. Failure to do this can result in phase shift of the amplifier.

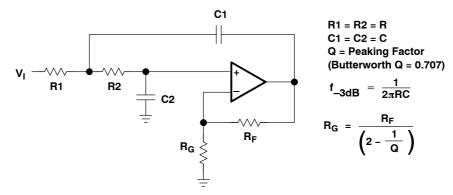


Figure 51. 2-Pole Low-Pass Sallen-Key Filter



SLOS219F - JUNE 1999 - REVISED DECEMBER 2011

APPLICATION INFORMATION

shutdown function

Three members of the TLC07x family (TLC070/3/5) have a shutdown terminal (SHDN) for conserving battery life in portable applications. When the shutdown terminal is tied low, the supply current is reduced to 125 μ A/channel, the amplifier is disabled, and the outputs are placed in a high-impedance mode. To enable the amplifier, the shutdown terminal can either be left floating or pulled high. When the shutdown terminal is left floating, care should be taken to ensure that parasitic leakage current at the shutdown terminal does not inadvertently place the operational amplifier into shutdown. The shutdown terminal threshold is always referenced to the voltage on the GND terminal of the device. Therefore, when operating the device with split supply voltages (e.g. ±2.5 V), the shutdown terminal needs to be pulled to V_{DD}- (not system ground) to disable the operational amplifier.

The amplifier's output with a shutdown pulse is shown in Figures 43 and 44. The amplifier is powered with a single 5-V supply and is configured as noninverting with a gain of 5. The amplifier turn-on and turn-off times are measured from the 50% point of the shutdown pulse to the 50% point of the output waveform. The times for the single, dual, and quad are listed in the data tables.

Figures 37, 38, 39, and 40 show the amplifier's forward and reverse isolation in shutdown. The operational amplifier is configured as a voltage follower ($A_V = 1$). The isolation performance is plotted across frequency using 0.1 V_{PP}, 2.5 V_{PP}, and 5 V_{PP} input signals at ±2.5 V supplies and 0.1 V_{PP}, 8 V_{PP}, and 12 V_{PP} input signals at ±6 V supplies.

circuit layout considerations

To achieve the levels of high performance of the TLC07x, follow proper printed-circuit board design techniques. A general set of guidelines is given in the following.

- Ground planes It is highly recommended that a ground plane be used on the board to provide all
 components with a low inductive ground connection. However, in the areas of the amplifier inputs and
 output, the ground plane can be removed to minimize the stray capacitance.
- Proper power supply decoupling Use a 6.8-µF tantalum capacitor in parallel with a 0.1-µF ceramic capacitor on each supply terminal. It may be possible to share the tantalum among several amplifiers depending on the application, but a 0.1-µF ceramic capacitor should always be used on the supply terminal of every amplifier. In addition, the 0.1-µF capacitor should be placed as close as possible to the supply terminal. As this distance increases, the inductance in the connecting trace makes the capacitor less effective. The designer should strive for distances of less than 0.1 inches between the device power terminals and the ceramic capacitors.
- Sockets Sockets can be used but are not recommended. The additional lead inductance in the socket pins
 will often lead to stability problems. Surface-mount packages soldered directly to the printed-circuit board
 is the best implementation.
- Short trace runs/compact part placements Optimum high performance is achieved when stray series inductance has been minimized. To realize this, the circuit layout should be made as compact as possible, thereby minimizing the length of all trace runs. Particular attention should be paid to the inverting input of the amplifier. Its length should be kept as short as possible. This will help to minimize stray capacitance at the input of the amplifier.
- Surface-mount passive components Using surface-mount passive components is recommended for high
 performance amplifier circuits for several reasons. First, because of the extremely low lead inductance of
 surface-mount components, the problem with stray series inductance is greatly reduced. Second, the small
 size of surface-mount components naturally leads to a more compact layout thereby minimizing both stray
 inductance and capacitance. If leaded components are used, it is recommended that the lead lengths be
 kept as short as possible.



SLOS219F - JUNE 1999 - REVISED DECEMBER 2011

APPLICATION INFORMATION

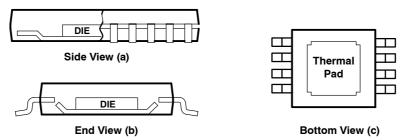
general PowerPAD design considerations

The TLC07x is available in a thermally-enhanced PowerPAD family of packages. These packages are constructed using a downset leadframe upon which the die is mounted [see Figure 52(a) and Figure 52(b)]. This arrangement results in the lead frame being exposed as a thermal pad on the underside of the package [see Figure 52(c)]. Because this thermal pad has direct thermal contact with the die, excellent thermal performance can be achieved by providing a good thermal path away from the thermal pad.

The PowerPAD package allows for both assembly and thermal management in one manufacturing operation. During the surface-mount solder operation (when the leads are being soldered), the thermal pad must be soldered to a copper area underneath the package. Through the use of thermal paths within this copper area, heat can be conducted away from the package into either a ground plane or other heat dissipating device.

Soldering the PowerPAD to the PCB is always required, even with applications that have low-power dissipation. This provides the necessary thermal and mechanical connection between the lead frame die pad and the PCB.

The PowerPAD package represents a breakthrough in combining the small area and ease of assembly of surface mount with mechanical methods of heatsinking.



NOTE A: The thermal pad is electrically isolated from all terminals in the package.

Figure 52. Views of Thermally-Enhanced DGN Package



SLOS219F - JUNE 1999 - REVISED DECEMBER 2011

APPLICATION INFORMATION

Although there are many ways to properly heatsink the PowerPAD package, the following steps illustrate the recommended approach.

general PowerPAD design considerations (continued)

- 1. The thermal pad must be connected to the same voltage potential as the GND pin.
- 2. Prepare the PCB with a top side etch pattern as illustrated in the thermal land pattern mechanical drawing at the end of this document. There should be etch for the leads as well as etch for the thermal pad.
- 3. Place five holes (single and dual) or nine holes (quad) in the area of the thermal pad. These holes should be 13 mils in diameter. Keep them small so that solder wicking through the holes is not a problem during reflow.
- 4. Additional vias may be placed anywhere along the thermal plane outside of the thermal pad area. This helps dissipate the heat generated by the TLC07x IC. These additional vias may be larger than the 13-mil diameter vias directly under the thermal pad. They can be larger because they are not in the thermal pad area to be soldered so that wicking is not a problem.
- 5. Connect all holes to the internal ground plane that is the same potential as the device GND pin.
- 6. When connecting these holes to the ground plane, do not use the typical web or spoke via connection methodology. Web connections have a high thermal resistance connection that is useful for slowing the heat transfer during soldering operations. This makes the soldering of vias that have plane connections easier. In this application, however, low thermal resistance is desired for the most efficient heat transfer. Therefore, the holes under the TLC07x PowerPAD package should make their connection to the internal ground plane with a complete connection around the entire circumference of the plated-through hole.
- 7. The top-side solder mask should leave the terminals of the package and the thermal pad area with its five holes (dual) or nine holes (quad) exposed. The bottom-side solder mask should cover the five or nine holes of the thermal pad area. This prevents solder from being pulled away from the thermal pad area during the reflow process.
- 8. Apply solder paste to the exposed thermal pad area and all of the IC terminals.
- 9. With these preparatory steps in place, the TLC07x IC is simply placed in position and run through the solder reflow operation as any standard surface-mount component. This results in a part that is properly installed.

For a given θ_{JA} , the maximum power dissipation is shown in Figure 54 and is calculated by the following formula:

$$\mathsf{P}_{\mathsf{D}} = \left(\frac{\mathsf{T}_{\mathsf{M}\mathsf{A}\mathsf{X}}^{-\mathsf{T}}\mathsf{A}}{\theta_{\mathsf{J}\mathsf{A}}}\right)$$

Where:

 P_D = Maximum power dissipation of TLC07x IC (watts) T_{MAX} = Absolute maximum junction temperature (150°C)

 T_A = Free-ambient air temperature (°C)

$$\theta_{JA} = \theta_{JC} + \theta_{CA}$$

 θ_{JC} = Thermal coefficient from junction to case

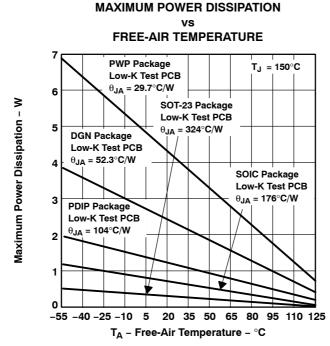
 θ_{CA} = Thermal coefficient from case to ambient air (°C/W)



SLOS219F - JUNE 1999 - REVISED DECEMBER 2011

APPLICATION INFORMATION

general PowerPAD design considerations (continued)



NOTE A: Results are with no air flow and using JEDEC Standard Low-K test PCB.

Figure 53. Maximum Power Dissipation vs Free-Air Temperature

The next consideration is the package constraints. The two sources of heat within an amplifier are quiescent power and output power. The designer should never forget about the quiescent heat generated within the device, especially multi-amplifier devices. Because these devices have linear output stages (Class A-B), most of the heat dissipation is at low output voltages with high output currents.

The other key factor when dealing with power dissipation is how the devices are mounted on the PCB. The PowerPAD devices are extremely useful for heat dissipation. But, the device should always be soldered to a copper plane to fully use the heat dissipation properties of the PowerPAD. The SOIC package, on the other hand, is highly dependent on how it is mounted on the PCB. As more trace and copper area is placed around the device, θ_{JA} decreases and the heat dissipation capability increases. The currents and voltages shown in these graphs are for the total package. For the dual or quad amplifier packages, the sum of the RMS output currents and voltages should be used to choose the proper package.



SLOS219F - JUNE 1999 - REVISED DECEMBER 2011

APPLICATION INFORMATION

macromodel information

Macromodel information provided was derived using Microsim *Parts*TM, the model generation software used with Microsim *PSpice*TM. The Boyle macromodel (see Note 1) and subcircuit in Figure 55 are generated using the TLC07x typical electrical and operating characteristics at $T_A = 25^{\circ}$ C. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification

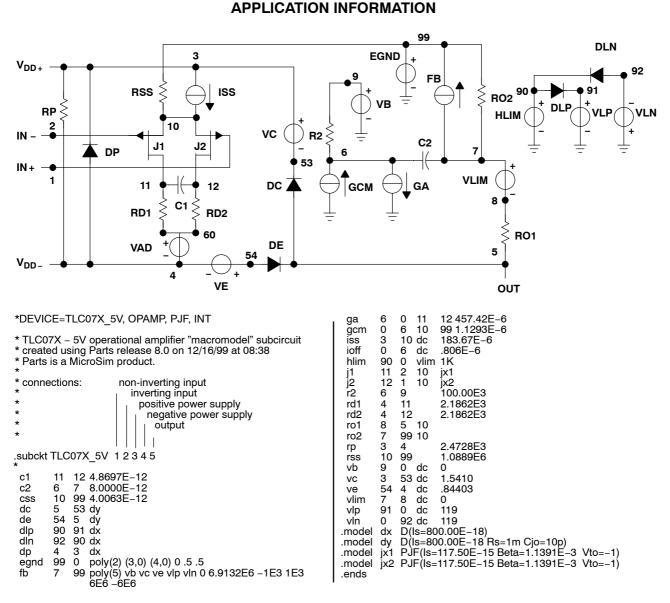
- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

PSpice and Parts are trademarks of MicroSim Corporation.



NOTE 2: G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers," *IEEE Journal of Solid-State Circuits,* SC-9, 353 (1974).

SLOS219F - JUNE 1999 - REVISED DECEMBER 2011









15-Apr-2017

PACKAGING INFORMATION

| Orderable Device | Status | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead/Ball Finish | MSL Peak Temp | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|--------|-------------------|--------------------|------|----------------|----------------------------|------------------|---------------------------|--------------|-------------------------|---------|
| TLC070AID | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | (6) CU NIPDAU | (3) Level-1-260C-UNLIM | -40 to 125 | C070AI | Samples |
| TLC070AIP | ACTIVE | PDIP | Р | 8 | 50 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | -40 to 125 | TLC070AI | Samples |
| TLC070AIPE4 | ACTIVE | PDIP | Р | 8 | 50 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | -40 to 125 | TLC070AI | Samples |
| TLC070CD | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | C070C | Samples |
| TLC070CDR | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | C070C | Samples |
| TLC070IDGNR | ACTIVE | MSOP- PowerPAD | DGN | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | ACT | Samples |
| TLC070IDR | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | C070I | Samples |
| TLC070IP | ACTIVE | PDIP | Ρ | 8 | 50 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | -40 to 125 | TLC070I | Samples |
| TLC071AID | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | C071AI | Samples |
| TLC071AIDG4 | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | C071AI | Samples |
| TLC071AIP | ACTIVE | PDIP | Р | 8 | 50 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | -40 to 125 | TLC071AI | Samples |
| TLC071AIPE4 | ACTIVE | PDIP | Р | 8 | 50 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | -40 to 125 | TLC071AI | Samples |
| TLC071CD | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | C071C | Samples |
| TLC071CDG4 | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | C071C | Samples |
| TLC071CDGN | ACTIVE | MSOP- PowerPAD | DGN | 8 | 80 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | ACU | Samples |
| TLC071CDGNR | ACTIVE | MSOP- PowerPAD | DGN | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | ACU | Samples |
| TLC071CDR | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | C071C | Samples |



15-Apr-2017

| Orderable Device | Status | Package Type | Package Drawing | Pins | Package Qty | Eco Plan | Lead/Ball Finish (6) | MSL Peak Temp | Op Temp (°C) | Device Marking (4/5) | Sam |
|------------------|--------|-------------------|--------------------|------|----------------|----------------------------|-------------------------|--------------------|--------------|-------------------------|-----|
| TLC071CP | ACTIVE | PDIP | P | 8 | 50 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | 0 to 70 | TLC071C | Sam |
| TLC071CPE4 | ACTIVE | PDIP | Р | 8 | 50 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | 0 to 70 | TLC071C | Sam |
| TLC071ID | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | C071I | San |
| TLC071IDG4 | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | C071I | San |
| TLC071IDGN | ACTIVE | MSOP- PowerPAD | DGN | 8 | 80 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | ACV | Sar |
| TLC071IDGNR | ACTIVE | MSOP- PowerPAD | DGN | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | ACV | Sar |
| TLC071IDR | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | C071I | Sar |
| TLC071IP | ACTIVE | PDIP | Р | 8 | 50 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | -40 to 125 | TLC071I | Sar |
| TLC072AID | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | C072AI | Sar |
| TLC072AIDG4 | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | C072AI | Sar |
| TLC072AIDR | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | C072AI | Sar |
| TLC072AIDRG4 | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | C072AI | Sar |
| TLC072AIP | ACTIVE | PDIP | Р | 8 | 50 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | -40 to 125 | C072AI | Sar |
| TLC072AIPE4 | ACTIVE | PDIP | Р | 8 | 50 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | -40 to 125 | C072AI | Sar |
| TLC072CD | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | C072C | Sar |
| TLC072CDG4 | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | C072C | Sar |
| TLC072CDGN | ACTIVE | MSOP- PowerPAD | DGN | 8 | 80 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | ADV | Sar |
| TLC072CDGNG4 | ACTIVE | MSOP- PowerPAD | DGN | 8 | 80 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | ADV | Sar |



15-Apr-2017

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead/Ball Finish (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samp |
|------------------|---------------|-------------------|--------------------|------|----------------|----------------------------|-------------------------|----------------------|--------------|-------------------------|------|
| TLC072CDGNR | ACTIVE | MSOP- PowerPAD | DGN | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | ADV | Samp |
| TLC072CDGNRG4 | ACTIVE | MSOP- PowerPAD | DGN | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | ADV | Samp |
| TLC072CDR | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | C072C | Samp |
| TLC072CDRG4 | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | C072C | Samp |
| TLC072CP | ACTIVE | PDIP | Р | 8 | 50 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | 0 to 70 | C072C | Samp |
| TLC072CPE4 | ACTIVE | PDIP | Р | 8 | 50 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | 0 to 70 | C072C | Samp |
| TLC072ID | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | C072I | Samp |
| TLC072IDG4 | ACTIVE | SOIC | D | 8 | 75 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | C072I | Samp |
| TLC072IDGN | ACTIVE | MSOP- PowerPAD | DGN | 8 | 80 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | ADW | Samp |
| TLC072IDGNG4 | ACTIVE | MSOP- PowerPAD | DGN | 8 | 80 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | ADW | Samp |
| TLC072IDGNR | ACTIVE | MSOP- PowerPAD | DGN | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | ADW | Samj |
| TLC072IDGNRG4 | ACTIVE | MSOP- PowerPAD | DGN | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | ADW | Samp |
| TLC072IDR | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | C072I | Samp |
| TLC072IDRG4 | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | C072I | Samp |
| TLC072IP | ACTIVE | PDIP | Р | 8 | 50 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | -40 to 125 | C072I | Samj |
| TLC072IPE4 | ACTIVE | PDIP | Р | 8 | 50 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | -40 to 125 | C072I | Samj |
| TLC073AID | ACTIVE | SOIC | D | 14 | 50 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | CO73AI | Samj |
| TLC073CDGQ | ACTIVE | MSOP- PowerPAD | DGQ | 10 | 80 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | ADX | Samj |



15-Apr-2017

| Orderable Device | Status | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead/Ball Finish (6) | MSL Peak Temp | Op Temp (°C) | Device Marking (4/5) | Sam |
|------------------|--------|-------------------|--------------------|------|----------------|----------------------------|-------------------------|--------------------|--------------|-------------------------|-----|
| TLC073CDGQG4 | ACTIVE | MSOP- PowerPAD | DGQ | 10 | 80 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | ADX | Sam |
| TLC073CDR | ACTIVE | SOIC | D | 14 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | C073C | Sam |
| TLC073IDGQ | ACTIVE | MSOP- PowerPAD | DGQ | 10 | 80 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | ADY | Sam |
| TLC073IDGQR | ACTIVE | MSOP- PowerPAD | DGQ | 10 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | ADY | San |
| TLC073IDGQRG4 | ACTIVE | MSOP- PowerPAD | DGQ | 10 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | ADY | San |
| TLC073IN | ACTIVE | PDIP | Ν | 14 | 25 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | -40 to 125 | C073I | Sar |
| TLC074AID | ACTIVE | SOIC | D | 14 | 50 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | TLC074AI | Sar |
| TLC074AIDG4 | ACTIVE | SOIC | D | 14 | 50 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | TLC074AI | Sar |
| TLC074AIDR | ACTIVE | SOIC | D | 14 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | TLC074AI | Sar |
| TLC074AIDRG4 | ACTIVE | SOIC | D | 14 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | TLC074AI | Sar |
| TLC074AIN | ACTIVE | PDIP | Ν | 14 | 25 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | -40 to 125 | TLC074AI | Sar |
| TLC074AIPWP | ACTIVE | HTSSOP | PWP | 20 | 70 | TBD | Call TI | Call TI | -40 to 125 | TLC074AI | Sar |
| TLC074CD | ACTIVE | SOIC | D | 14 | 50 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | TLC074C | Sar |
| TLC074CDG4 | ACTIVE | SOIC | D | 14 | 50 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | TLC074C | Sar |
| TLC074CDR | ACTIVE | SOIC | D | 14 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | TLC074C | Sar |
| TLC074CDRG4 | ACTIVE | SOIC | D | 14 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | TLC074C | Sar |
| TLC074CN | ACTIVE | PDIP | Ν | 14 | 25 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | 0 to 70 | TLC074C | Sar |
| TLC074CNE4 | ACTIVE | PDIP | Ν | 14 | 25 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | 0 to 70 | TLC074C | Sar |



15-Apr-2017

| Orderable Device | Status | Package Type | Package Drawing | Pins | | Eco Plan | Lead/Ball Finish | MSL Peak Temp | Op Temp (°C) | Device Marking | Samp |
|------------------|--------|--------------|--------------------|------|------|----------------------------|------------------|---------------------|--------------|----------------|------|
| | (1) | | | | Qty | (2) | (6) | (3) | | (4/5) | |
| TLC074CPWP | ACTIVE | HTSSOP | PWP | 20 | 70 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR | 0 to 70 | TLC074C | Samp |
| TLC074CPWPG4 | ACTIVE | HTSSOP | PWP | 20 | 70 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR | 0 to 70 | TLC074C | Samp |
| TLC074CPWPR | ACTIVE | HTSSOP | PWP | 20 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR | 0 to 70 | TLC074C | Samp |
| TLC074ID | ACTIVE | SOIC | D | 14 | 50 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | TLC074I | Samj |
| TLC074IDG4 | ACTIVE | SOIC | D | 14 | 50 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | TLC074I | Samj |
| TLC074IDR | ACTIVE | SOIC | D | 14 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | TLC074I | Sam |
| TLC074IDRG4 | ACTIVE | SOIC | D | 14 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | TLC074I | Sam |
| TLC074IN | ACTIVE | PDIP | Ν | 14 | 25 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | -40 to 125 | TLC074I | Sam |
| TLC074IPWP | ACTIVE | HTSSOP | PWP | 20 | 70 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | TLC074I | Sam |
| TLC075AID | ACTIVE | SOIC | D | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | TLC075AI | Sam |
| TLC075AIDR | ACTIVE | SOIC | D | 16 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | TLC075AI | Sam |
| TLC075AIDRG4 | ACTIVE | SOIC | D | 16 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 125 | TLC075AI | Sam |
| TLC075AIN | ACTIVE | PDIP | Ν | 16 | 25 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | -40 to 125 | TLC075AI | Sam |
| TLC075AIPWP | ACTIVE | HTSSOP | PWP | 20 | 70 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | TLC075AI | Sam |
| TLC075CD | ACTIVE | SOIC | D | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | 0 to 70 | TLC075C | Sam |
| TLC075CPWP | ACTIVE | HTSSOP | PWP | 20 | 70 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR | 0 to 70 | TLC075C | Sam |
| TLC075IPWP | ACTIVE | HTSSOP | PWP | 20 | 70 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-2-260C-1 YEAR | -40 to 125 | TLC075I | Sam |

⁽¹⁾ The marketing status values are defined as follows:



www.ti.com

15-Apr-2017

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect. NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design. PREVIEW: Device has been announced but is not in production. Samples may or may not be available. OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TLC072 :

Automotive: TLC072-Q1

NOTE: Qualified Version Definitions:



15-Apr-2017

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

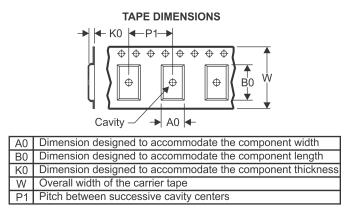
PACKAGE MATERIALS INFORMATION

www.ti.com

Texas Instruments

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-------------|-----------------------|--------------------|------|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| TLC070CDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| TLC070IDGNR | MSOP- Power PAD | DGN | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| TLC070IDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| TLC070IDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| TLC071CDGNR | MSOP- Power PAD | DGN | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| TLC071CDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| TLC071IDGNR | MSOP- Power PAD | DGN | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| TLC071IDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| TLC072AIDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| TLC072CDGNR | MSOP- Power PAD | DGN | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| TLC072CDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| TLC072CDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |

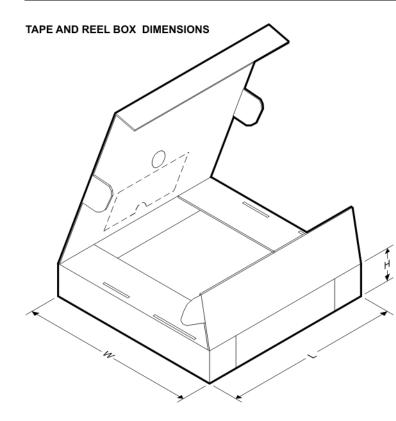
PACKAGE MATERIALS INFORMATION



www.ti.com

3-Aug-2017

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-------------|-----------------------|--------------------|------|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| TLC072IDGNR | MSOP- Power PAD | DGN | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| TLC072IDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| TLC073CDR | SOIC | D | 14 | 2500 | 330.0 | 16.4 | 6.5 | 9.0 | 2.1 | 8.0 | 16.0 | Q1 |
| TLC073IDGQR | MSOP- Power PAD | DGQ | 10 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| TLC074AIDR | SOIC | D | 14 | 2500 | 330.0 | 16.4 | 6.5 | 9.0 | 2.1 | 8.0 | 16.0 | Q1 |
| TLC074CDR | SOIC | D | 14 | 2500 | 330.0 | 16.4 | 6.5 | 9.0 | 2.1 | 8.0 | 16.0 | Q1 |
| TLC074CDR | SOIC | D | 14 | 2500 | 330.0 | 16.4 | 6.5 | 9.0 | 2.1 | 8.0 | 16.0 | Q1 |
| TLC074CPWPR | HTSSOP | PWP | 20 | 2000 | 330.0 | 16.4 | 6.95 | 7.1 | 1.6 | 8.0 | 16.0 | Q1 |
| TLC074IDR | SOIC | D | 14 | 2500 | 330.0 | 16.4 | 6.5 | 9.0 | 2.1 | 8.0 | 16.0 | Q1 |
| TLC075AIDR | SOIC | D | 16 | 2500 | 330.0 | 16.4 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-------------|---------------|-----------------|------|------|-------------|------------|-------------|
| TLC070CDR | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| TLC070IDGNR | MSOP-PowerPAD | DGN | 8 | 2500 | 358.0 | 335.0 | 35.0 |
| TLC070IDR | SOIC | D | 8 | 2500 | 367.0 | 367.0 | 38.0 |
| TLC070IDR | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |

PACKAGE MATERIALS INFORMATION



www.ti.com

3-Aug-2017

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-------------|---------------|-----------------|------|------|-------------|------------|-------------|
| TLC071CDGNR | MSOP-PowerPAD | DGN | 8 | 2500 | 358.0 | 335.0 | 35.0 |
| TLC071CDR | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| TLC071IDGNR | MSOP-PowerPAD | DGN | 8 | 2500 | 358.0 | 335.0 | 35.0 |
| TLC071IDR | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| TLC072AIDR | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| TLC072CDGNR | MSOP-PowerPAD | DGN | 8 | 2500 | 358.0 | 335.0 | 35.0 |
| TLC072CDR | SOIC | D | 8 | 2500 | 367.0 | 367.0 | 38.0 |
| TLC072CDR | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| TLC072IDGNR | MSOP-PowerPAD | DGN | 8 | 2500 | 358.0 | 335.0 | 35.0 |
| TLC072IDR | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| TLC073CDR | SOIC | D | 14 | 2500 | 367.0 | 367.0 | 38.0 |
| TLC073IDGQR | MSOP-PowerPAD | DGQ | 10 | 2500 | 358.0 | 335.0 | 35.0 |
| TLC074AIDR | SOIC | D | 14 | 2500 | 367.0 | 367.0 | 38.0 |
| TLC074CDR | SOIC | D | 14 | 2500 | 333.2 | 345.9 | 28.6 |
| TLC074CDR | SOIC | D | 14 | 2500 | 367.0 | 367.0 | 38.0 |
| TLC074CPWPR | HTSSOP | PWP | 20 | 2000 | 367.0 | 367.0 | 38.0 |
| TLC074IDR | SOIC | D | 14 | 2500 | 367.0 | 367.0 | 38.0 |
| TLC075AIDR | SOIC | D | 16 | 2500 | 367.0 | 367.0 | 38.0 |

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PWP (R-PDSO-G20)

PowerPAD[™] PLASTIC SMALL OUTLINE



All linear dimensions are in millimeters. NOTES: Α.

- Β. This drawing is subject to change without notice.
- Body dimensions do not include mold flash or protrusions. Mold flash and protrusion shall not exceed 0.15 per side. C.
- This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad D.
- Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com http://www.ti.com. E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions. E. Falls within JEDEC MO-153



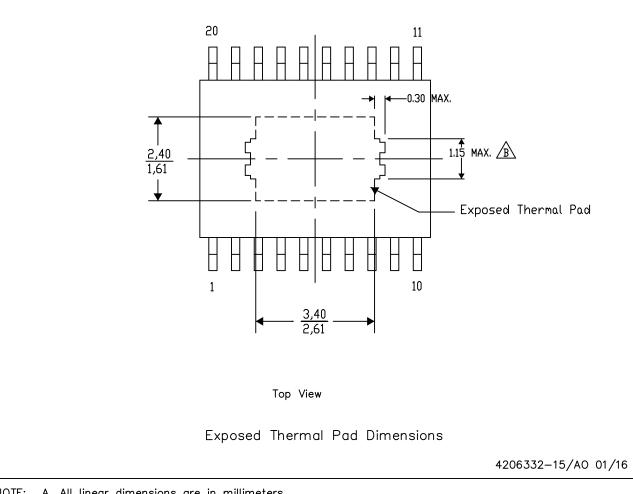
PowerPAD[™] SMALL PLASTIC OUTLINE PWP (R-PDSO-G20)

THERMAL INFORMATION

This PowerPAD[™] package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



NOTE: A. All linear dimensions are in millimeters

A Exposed tie strap features may not be present.





NOTES:

Α.

B. This drawing is subject to change without notice.

All linear dimensions are in millimeters.

- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
- F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



P(R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



DGQ (S-PDSO-G10)

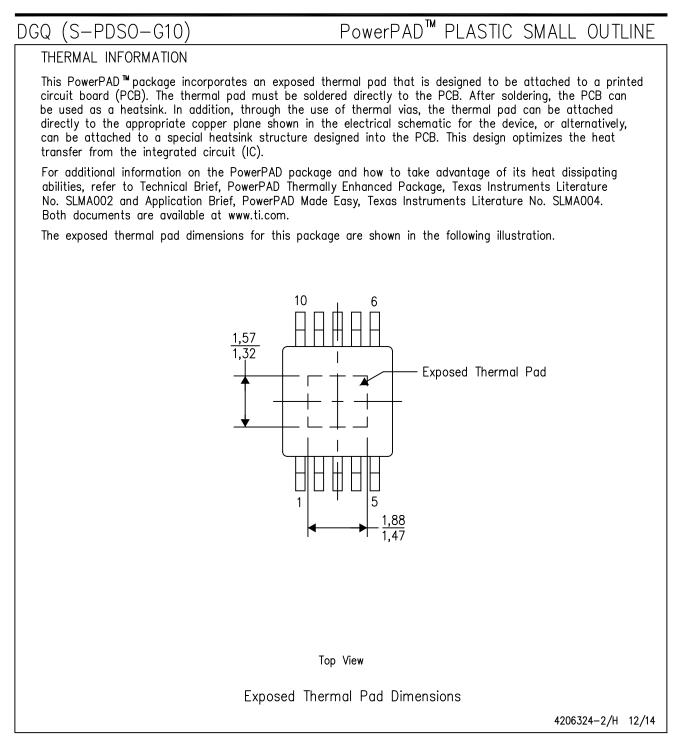
PowerPAD[™] PLASTIC SMALL OUTLINE



NOTES: Α. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com http://www.ti.com.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
 F. Falls within JEDEC MO-187 variation BA-T.





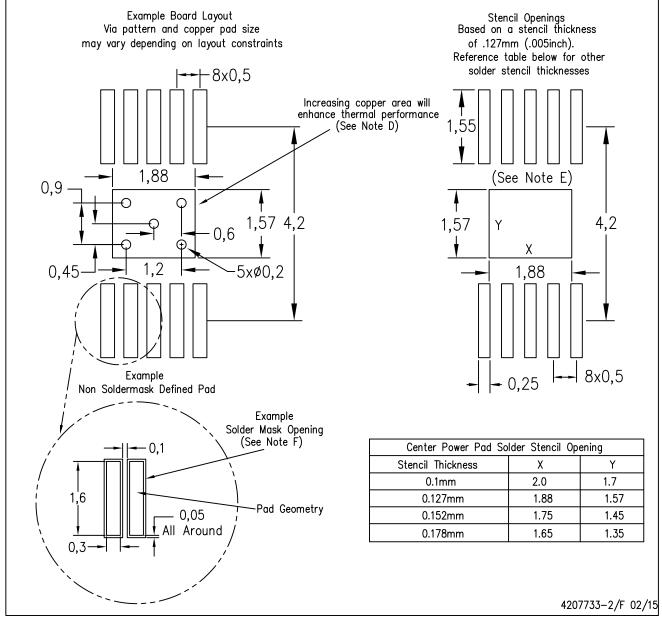
NOTE: A. All linear dimensions are in millimeters



LAND PATTERN DATA

DGQ (S-PDSO-G10)

PowerPAD[™] PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at
- www.ti.com http://www.ti.com. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
- F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DGN (S-PDSO-G8)

PowerPAD[™] PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com http://www.ti.com.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
 F. Falls within JEDEC MO-187 variation AA-T



DGN (S-PDSO-G8)

PowerPAD[™] PLASTIC SMALL OUTLINE

THERMAL INFORMATION

This PowerPAD M package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.





4206323-2/1 12/11

NOTE: All linear dimensions are in millimeters



DGN (R-PDSO-G8)

PowerPAD[™] PLASTIC SMALL OUTLINE



NOTES:

- : A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
 - D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com.
 - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
- F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



4211283-4/E 08/12

D (R-PDSO-G16) PLASTIC SMALL OUTLINE Stencil Openings (Note D) Example Board Layout (Note C) –16x0,55 -14x1,27 -14x1,27 16x1,50 5,40 5.40 Example Non Soldermask Defined Pad Example Pad Geometry (See Note C) 0,60 .55 Example 1. Solder Mask Opening (See Note E) -0,07 All Around

NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



IMPORTANT NOTICE

Texas Instruments Incorporated (TI) reserves the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete.

TI's published terms of sale for semiconductor products (http://www.ti.com/sc/docs/stdterms.htm) apply to the sale of packaged integrated circuit products that TI has qualified and released to market. Additional terms may apply to the use or sale of other types of TI products and services.

Reproduction of significant portions of TI information in TI data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such reproduced documentation. Information of third parties may be subject to additional restrictions. Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyers and others who are developing systems that incorporate TI products (collectively, "Designers") understand and agree that Designers remain responsible for using their independent analysis, evaluation and judgment in designing their applications and that Designers have full and exclusive responsibility to assure the safety of Designers' applications and compliance of their applications (and of all TI products used in or for Designers' applications) with all applicable regulations, laws and other applicable requirements. Designer represents that, with respect to their applications, Designer has all the necessary expertise to create and implement safeguards that (1) anticipate dangerous consequences of failures, (2) monitor failures and their consequences, and (3) lessen the likelihood of failures that might cause harm and take appropriate actions. Designer agrees that prior to using or distributing any applications that include TI products, Designer will thoroughly test such applications and the functionality of such TI products as used in such applications.

TI's provision of technical, application or other design advice, quality characterization, reliability data or other services or information, including, but not limited to, reference designs and materials relating to evaluation modules, (collectively, "TI Resources") are intended to assist designers who are developing applications that incorporate TI products; by downloading, accessing or using TI Resources in any way, Designer (individually or, if Designer is acting on behalf of a company, Designer's company) agrees to use any particular TI Resource solely for this purpose and subject to the terms of this Notice.

TI's provision of TI Resources does not expand or otherwise alter TI's applicable published warranties or warranty disclaimers for TI products, and no additional obligations or liabilities arise from TI providing such TI Resources. TI reserves the right to make corrections, enhancements, improvements and other changes to its TI Resources. TI has not conducted any testing other than that specifically described in the published documentation for a particular TI Resource.

Designer is authorized to use, copy and modify any individual TI Resource only in connection with the development of applications that include the TI product(s) identified in such TI Resource. NO OTHER LICENSE, EXPRESS OR IMPLIED, BY ESTOPPEL OR OTHERWISE TO ANY OTHER TI INTELLECTUAL PROPERTY RIGHT, AND NO LICENSE TO ANY TECHNOLOGY OR INTELLECTUAL PROPERTY RIGHT OF TI OR ANY THIRD PARTY IS GRANTED HEREIN, including but not limited to any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information regarding or referencing third-party products or services does not constitute a license to use such products or services, or a warranty or endorsement thereof. Use of TI Resources may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

TI RESOURCES ARE PROVIDED "AS IS" AND WITH ALL FAULTS. TI DISCLAIMS ALL OTHER WARRANTIES OR REPRESENTATIONS, EXPRESS OR IMPLIED, REGARDING RESOURCES OR USE THEREOF, INCLUDING BUT NOT LIMITED TO ACCURACY OR COMPLETENESS, TITLE, ANY EPIDEMIC FAILURE WARRANTY AND ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, AND NON-INFRINGEMENT OF ANY THIRD PARTY INTELLECTUAL PROPERTY RIGHTS. TI SHALL NOT BE LIABLE FOR AND SHALL NOT DEFEND OR INDEMNIFY DESIGNER AGAINST ANY CLAIM, INCLUDING BUT NOT LIMITED TO ANY INFRINGEMENT CLAIM THAT RELATES TO OR IS BASED ON ANY COMBINATION OF PRODUCTS EVEN IF DESCRIBED IN TI RESOURCES OR OTHERWISE. IN NO EVENT SHALL TI BE LIABLE FOR ANY ACTUAL, DIRECT, SPECIAL, COLLATERAL, INDIRECT, PUNITIVE, INCIDENTAL, CONSEQUENTIAL OR EXEMPLARY DAMAGES IN CONNECTION WITH OR ARISING OUT OF TI RESOURCES OR USE THEREOF, AND REGARDLESS OF WHETHER TI HAS BEEN ADVISED OF THE POSSIBILITY OF SUCH DAMAGES.

Unless TI has explicitly designated an individual product as meeting the requirements of a particular industry standard (e.g., ISO/TS 16949 and ISO 26262), TI is not responsible for any failure to meet such industry standard requirements.

Where TI specifically promotes products as facilitating functional safety or as compliant with industry functional safety standards, such products are intended to help enable customers to design and create their own applications that meet applicable functional safety standards and requirements. Using products in an application does not by itself establish any safety features in the application. Designers must ensure compliance with safety-related requirements and standards applicable to their applications. Designer may not use any TI products in life-critical medical equipment unless authorized officers of the parties have executed a special contract specifically governing such use. Life-critical medical equipment is medical equipment where failure of such equipment would cause serious bodily injury or death (e.g., life support, pacemakers, defibrillators, heart pumps, neurostimulators, and implantables). Such equipment includes, without limitation, all medical devices identified by the U.S. Food and Drug Administration as Class III devices and equivalent classifications outside the U.S.

TI may expressly designate certain products as completing a particular qualification (e.g., Q100, Military Grade, or Enhanced Product). Designers agree that it has the necessary expertise to select the product with the appropriate qualification designation for their applications and that proper product selection is at Designers' own risk. Designers are solely responsible for compliance with all legal and regulatory requirements in connection with such selection.

Designer will fully indemnify TI and its representatives against any damages, costs, losses, and/or liabilities arising out of Designer's noncompliance with the terms and provisions of this Notice.

> Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2017, Texas Instruments Incorporated